

## FMG2G75US120

### Molding Type Module

#### General Description

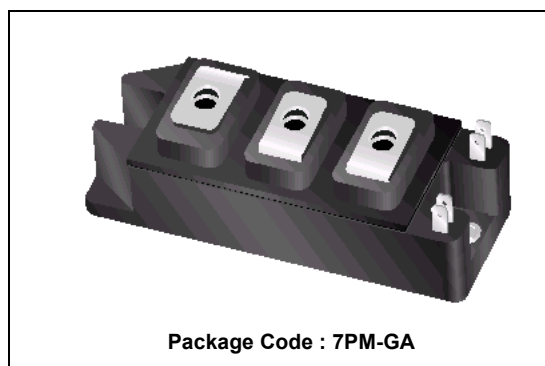
Fairchild IGBT Power Module provides low conduction and switching losses as well as short circuit ruggedness. It's designed for the applications such as motor control, uninterrupted power supplies (UPS) and general inverters where short-circuit ruggedness is required.

#### Features

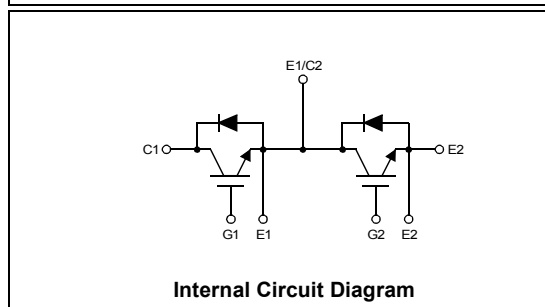
- Short Circuit Rated Time; 10us @  $T_C = 100^\circ\text{C}$ ,  $V_{GE} = 15\text{V}$
- High Speed Switching
- Low Saturation Voltage :  $V_{CE(sat)} = 2.6\text{V}$  @  $I_C = 75\text{A}$
- High Input Impedance
- Fast & Soft Anti-Parallel FWD
- UL Certified No.E209204

#### Application

- AC & DC Motor Controls
- General Purpose Inverters
- Weldings
- Servo Controls
- UPS



Package Code : 7PM-GA



Internal Circuit Diagram

#### Absolute Maximum Ratings $T_C = 25^\circ\text{C}$ unless otherwise noted

Symbol	Description	FMG2G75US120	Units
$V_{CES}$	Collector-Emitter Voltage	1200	V
$V_{GES}$	Gate-Emitter Voltage	$\pm 20$	V
$I_C$	Collector Current	75	A
$I_{CM(1)}$	Pulsed Collector Current	150	A
$I_F$	Diode Continuous Forward Current	75	A
$I_{FM}$	Diode Maximum Forward Current	150	A
$P_D$	Maximum Power Dissipation	445	W
$T_{SC}$	Short Circuit Withstand Time @ $T_C = 100^\circ\text{C}$	10	us
$T_J$	Operating Junction Temperature	-40 to +150	$^\circ\text{C}$
$T_{STG}$	Storage Temperature Range	-40 to +125	$^\circ\text{C}$
$V_{ISO}$	Isolation Voltage @ AC 1minute	2500	V
Mounting Torque	Power Terminal Screw : M5	4.0	N.m
	Mounting Screw : M5	4.0	N.m

**Notes :**

(1) Repetitive rating : Pulse width limited by max. junction temperature

### Electrical Characteristics of IGBT T<sub>C</sub> = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
<b>Off Characteristics</b>						
$V_{CES}$	Collector-Emitter Breakdown Voltage	$V_{GE} = 0V, I_C = 3mA$	1200	--	--	V
$\Delta V_{CES} / \Delta T_J$	Temperature Coeff. of Breakdown Voltage	$V_{GE} = 0V, I_C = 1mA$	--	0.6	--	V/°C
$I_{CES}$	Collector Cut-Off Current	$V_{CE} = V_{CES}, V_{GE} = 0V$	--	--	3	mA
$I_{GES}$	Gate - Emitter Leakage Current	$V_{GE} = V_{GES}, V_{CE} = 0V$	--	--	± 100	nA

### On Characteristics

$V_{GE(th)}$	Gate - Emitter Threshold Voltage	$I_C = 75mA, V_{CE} = V_{GE}$	5.0	7.0	8.5	V
$V_{CE(sat)}$	Collector to Emitter Saturation Voltage	$I_C = 75A, V_{GE} = 15V$	--	2.6	3.0	V

### Switching Characteristics

$t_{d(on)}$	Turn-On Delay Time	$V_{CC} = 600V, I_C = 75A,$ $R_G = 10\Omega, V_{GE} = 15V,$ Inductive Load, $T_C = 25^\circ C$	--	75	--	ns
$t_r$	Rise Time		--	80	--	ns
$t_{d(off)}$	Turn-Off Delay Time		--	295	--	ns
$t_f$	Fall Time		--	50	150	ns
$E_{on}$	Turn-On Switching Loss		--	6.9	--	mJ
$E_{off}$	Turn-Off Switching Loss	--	4.3	--	mJ	
$t_{d(on)}$	Turn-On Delay Time	$V_{CC} = 600V, I_C = 75A,$ $R_G = 10\Omega, V_{GE} = 15V,$ Inductive Load, $T_C = 125^\circ C$	--	80	--	ns
$t_r$	Rise Time		--	80	--	ns
$t_{d(off)}$	Turn-Off Delay Time		--	310	--	ns
$t_f$	Fall Time		--	70	--	ns
$E_{on}$	Turn-On Switching Loss		--	8.4	--	mJ
$E_{off}$	Turn-Off Switching Loss	--	5.6	--	mJ	
$T_{sc}$	Short Circuit Withstand Time	$V_{CC} = 600V, V_{GE} = 15V$ @ $T_C = 100^\circ C$	10	--	--	us
$Q_g$	Total Gate Charge	$V_{CE} = 300V, I_C = 75A,$ $V_{GE} = 15V$	--	570	--	nC
$Q_{ge}$	Gate-Emitter Charge		--	90	--	nC
$Q_{gc}$	Gate-Collector Charge		--	310	--	nC

### Electrical Characteristics of DIODE T<sub>C</sub> = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units	
$V_{FM}$	Diode Forward Voltage	$I_F = 75A$	$T_C = 25^\circ C$	--	2.3	3.0	V
			$T_C = 125^\circ C$	--	2.2	--	
$t_{rr}$	Diode Reverse Recovery Time	$I_F = 75A$ $di/dt = 1000 A/us$	$T_C = 25^\circ C$	--	150	--	ns
			$T_C = 125^\circ C$	--	225	--	
$I_{rr}$	Diode Peak Reverse Recovery Current	$I_F = 75A$ $di/dt = 1000 A/us$	$T_C = 25^\circ C$	--	47	--	A
			$T_C = 125^\circ C$	--	61	--	
$Q_{rr}$	Diode Reverse Recovery Charge	$I_F = 75A$ $di/dt = 1000 A/us$	$T_C = 25^\circ C$	--	3525	--	nC
			$T_C = 125^\circ C$	--	6863	--	

### Thermal Characteristics

Symbol	Parameter	Typ.	Max.	Units
$R_{\theta JC}$	Junction-to-Case (IGBT Part, per 1/2 Module)	--	0.28	°C/W
$R_{\theta JC}$	Junction-to-Case (DIODE Part, per 1/2 Module)	--	0.34	°C/W
$R_{\theta JC}$	Case-to-Sink (Conductive grease applied)	0.035	--	°C/W
Weight	Weight of Module	240	--	g

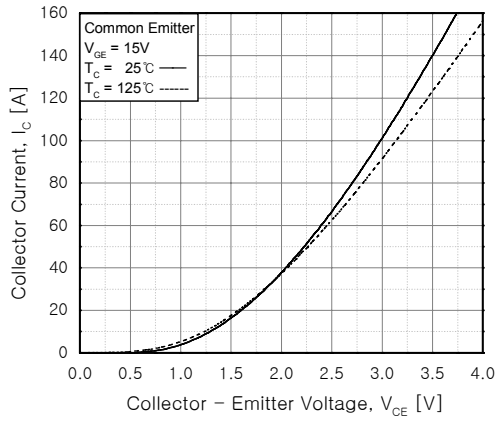


Fig 1. Typical Output Characteristics

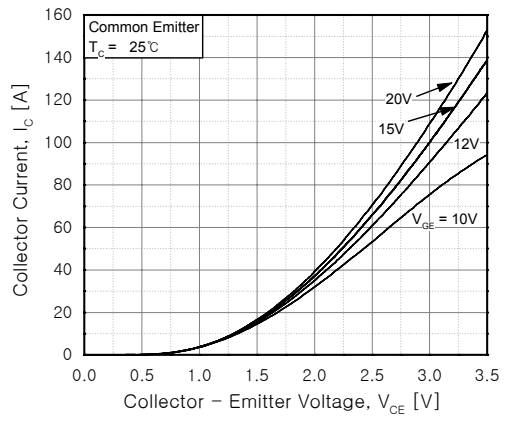


Fig 2. Typical Saturation Voltage Characteristics

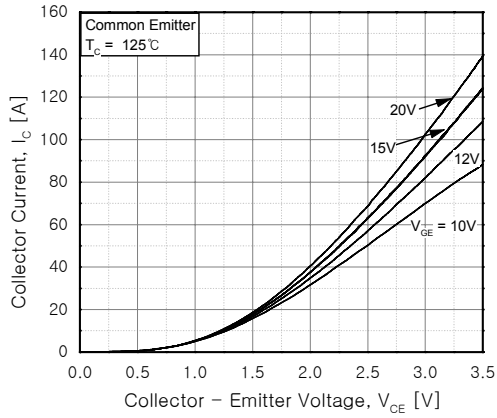


Fig 3. Typical Saturation Voltage Characteristics

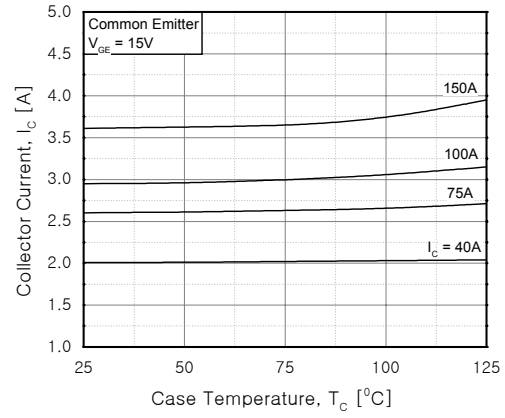


Fig 4. Saturation Voltage vs. Case Temperature at Variant Current Level

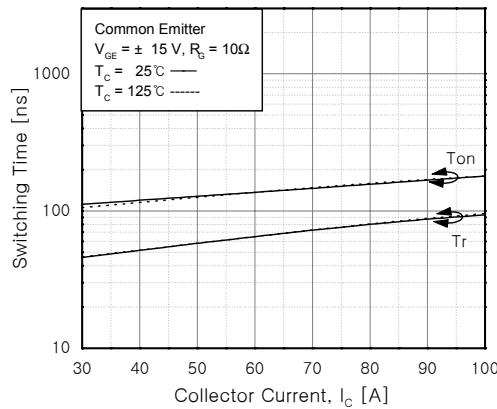


Fig 5. Turn-On Characteristics vs. Collector Current

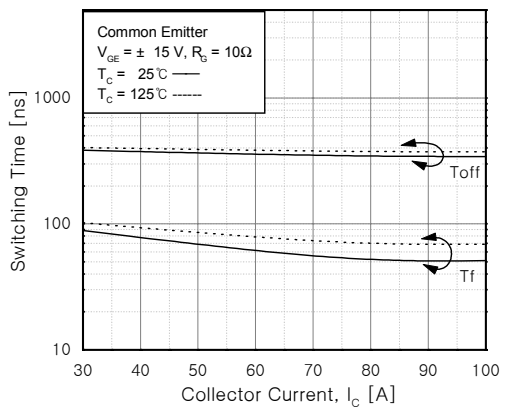


Fig 6. Turn-Off Characteristics vs. Collector Current

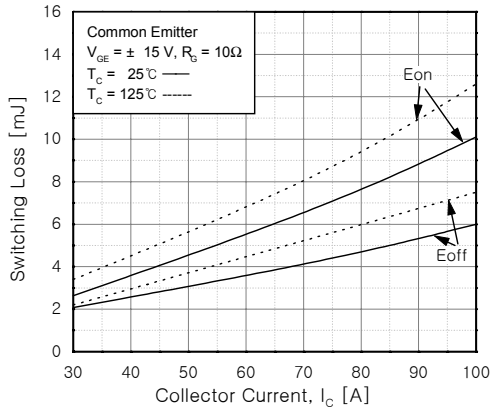


Fig 7. Switching Loss vs. Collector Current

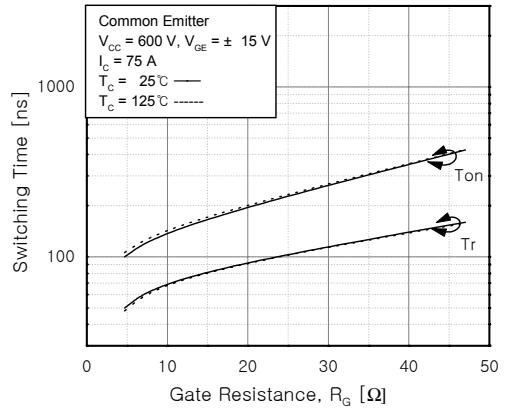


Fig 8. Turn-on Characteristics vs. Gate Resistance

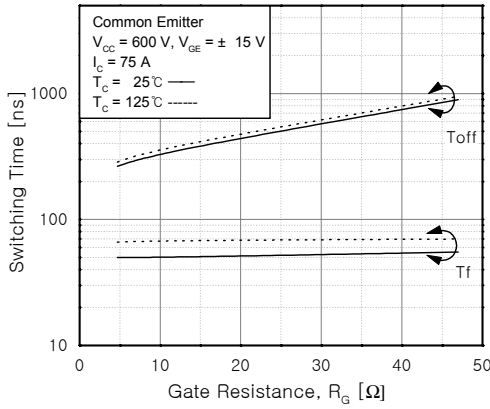


Fig 9. Turn-Off Characteristics vs. Gate Resistance

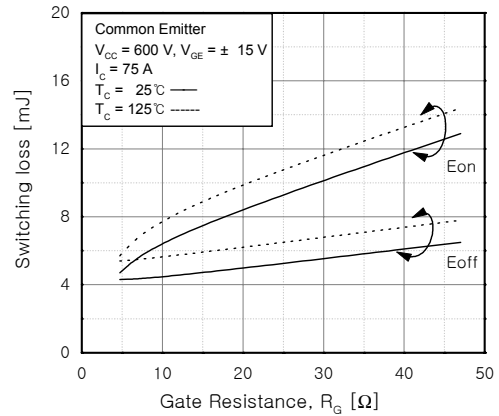


Fig 10. Switching Loss vs. Gate Resistance

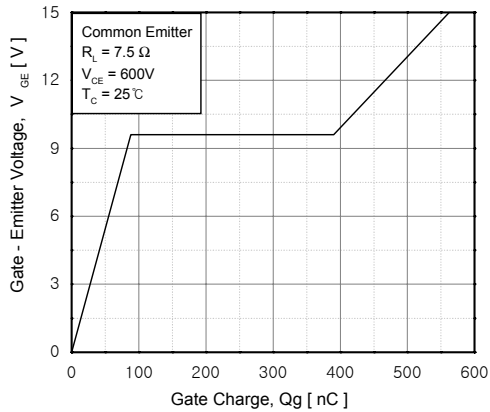


Fig 11. Gate Charge Characteristics

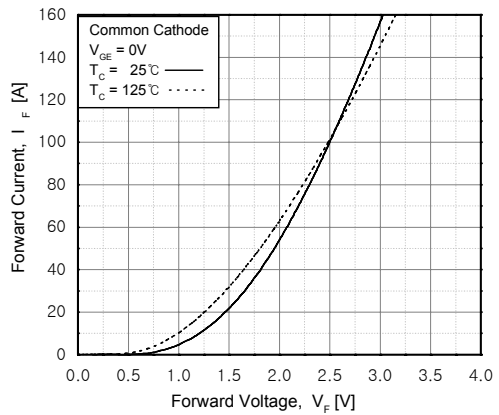


Fig 12. Forward Characteristics(diode)

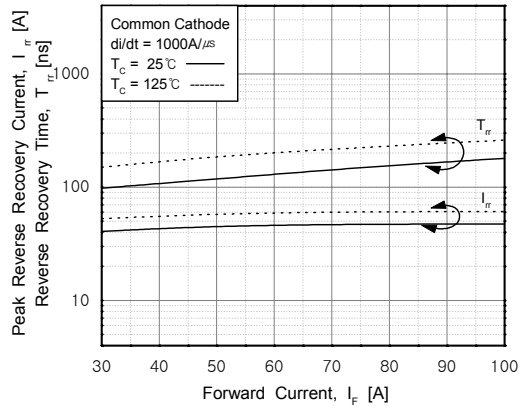
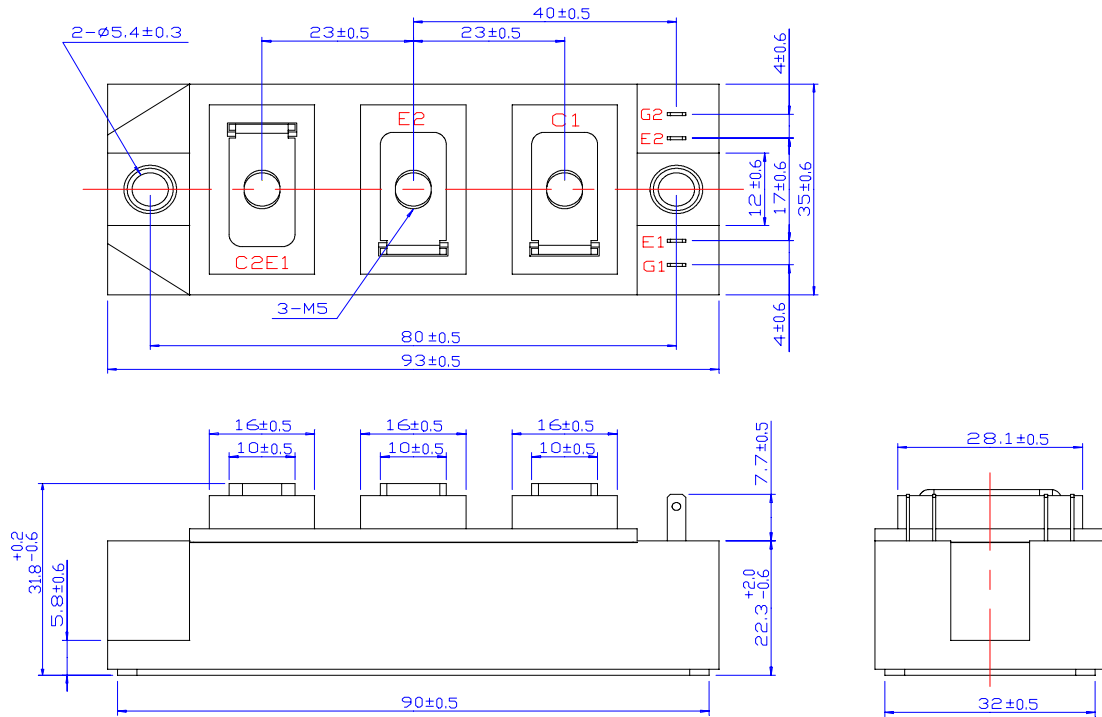


Fig 13. Reverse Recovery Characteristics(diode)

Dimensions in Millimeters

Package Dimension

7PM-GA



Dimensions in Millimeters

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EcoSPARK™	HiSeC™	MSX™	Quiet Series™	TINYOPTO™
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EnSigna™	i-Lo™	OCX™	RapidConnect™	UHC™
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